UHF AND ULTRA-FAST SWITCHING ($T_A = 25^\circ\text{C}$)

Type	V_{RRM} (V)	I_F (mA)	I_R^* max (μA)	@ V_R (V)	V_F^* max (V)	@ I_F (mA)	C @ V_R max F = 1 MHz (pF) (V)		Dynamic parameters	Package
BAR 19	4	30	0.25	3	0.6	10	1	1	F = < 6 dB / 1 GHz Q _s < 3 pC / 10 mA τ < 100 ps / 20 mA t _{rr} < 1 ns / 3 mA τ < 100 ps / 5 mA τ < 100 ps / 5 mA	DO35 GLASS
BAT 29	5	30	0.05	1	0.55	10	1	0		
BAT 19	10	30	0.1	5	0.4	1	1.2	0		
BAT 45	15	30	0.1	6	0.5	10	1.1	1		
• 1N 5711	70	15	0.2	50	0.41	1	2	0		
• 1N 6263	60	15	0.2	50	0.41	1	2.2	0		
TMM BAT 29	5	30	0.05	1	0.55	10	1	0	Q _s < 3 pC / 10 mA τ < 100 ps / 20 mA t _{rr} < 1 ns / 3 mA τ < 100 ps / 5 mA	MINIMELF GLASS
TMM BAT 19	10	30	0.1	5	0.4	1	1.2	0		
TMM BAT 45	15	30	0.1	6	0.5	10	1.1	1		
• TMM 6263	60	15	0.2	50	0.41	1	2.2	0		

• Preferred device.

F: Mixer noise figure.

Q_s: Stored charges (B-line) τ : Minority carrier file time (Kraukauer method).* Pulse test $t_p \leq 300 \mu\text{s}$, $\delta < 2\%$

UHF AND ULTRA-FAST SWITCHING (T_A= 25°C)

Type	Marking	Config.	Maximum ratings		I _R * @ V _R		V _F * @ I _F		C @ V _R F = 1 MHz		Dynamic parameters	Package	
			V _{RRM}	I _F	max		min	max	max				
			(V)	(mA)	(μA)	(V)	(V)	(mA)	(pF)	(V)			
BAR 18	D76	1	70	15	0.2	50		0.41	1	2	0	τ < 100ps @ 5mA	SOT23 PLASTIC
• BAR 42	D94	1	30	100	0.5	25		0.4	10	7#	1	t _{rr} < 5ns @ 10mA	
• BAR 43	D95	1	30	100	0.5	25	0.26	0.33	2	7#	1	t _{rr} < 5ns @ 10mA	
BAR 46	S46	1	100	150	5	75	-	0.25	0.10	6#	1	t _{rr} < 5ns @ 10μA	
BAS 70-06	D98	2	70	15	0.2	50		0.41	1	2	0	τ < 100ps @ 5mA	
• BAR 43 A	DB1	2	30	100	0.5	25	0.26	0.33	2	7#	1	t _{rr} < 5ns @ 10mA	
BAR 46 A	A46	2	100	150	5	75	-	0.25	0.10	6#	1	t _{rr} < 5ns @ 10μA	
BAS 70-05	D97	3	70	15	0.2	50		0.41	1	2	0	τ < 100ps @ 5mA	
• BAR 43 C	DB2	3	30	100	0.5	25	0.26	0.33	2	7#	1	t _{rr} < 5ns @ 10mA	
BAS 70-04	D96	4	70	15	0.2	50		0.41	1	2	0	τ < 100ps @ 5mA	
• BAR 43 S	DA5	4	30	100	0.5	25	0.26	0.33	2	7#	1	t _{rr} < 5ns @ 10mA	

• Preferred device.

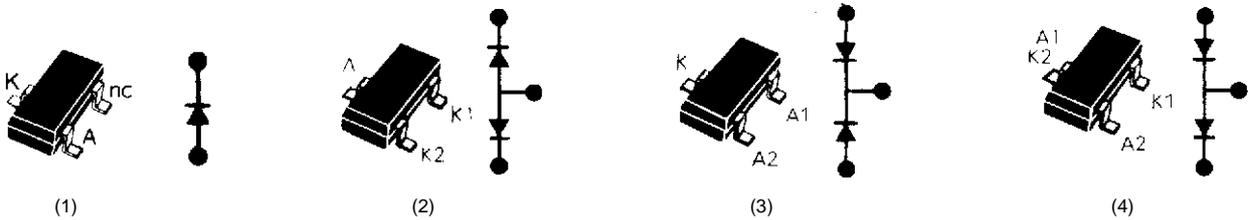
F Mixer noise figure.

τ Minority carrier lifetime (Krakauer method).

Typical value.

* pulse test tp ≤ 300 μs, δ < 2%.

Configurations



GENERAL PURPOSE ($T_A = 25^\circ\text{C}$)

Type	V_{RRM} (V)	I_F (mA)	$I_R^* @ V_R$		$V_F^* @ I_F$		$C @ V_R$ $F = 1 \text{ MHz}$		Dynamic parameters	Package
			max (μ)	(V)	max (V)	(mA)	Typ (pF)	(V)		
• BAT 42	30	200	0.5	25	{ 0.4 10 0.65 50 1 200	7	1	$t_{rr} < 5 \text{ ns}$	/10 mA	DO35 GLASS
BAT 43	30	200	0.5	25	{ 0.45 15 1 200	7	1	$\eta > 80\%$	/45 MHz	
• BAT 47	20	350	4	10	{ 0.25 0.1 0.4 10 1 300	12	1	$t_{rr} < 10 \text{ ns}$	/10 mA	
• BAT 48	40	350	2	10	{ 0.25 0.1 0.4 10 0.9 500	12	1	$t_{rr} < 10 \text{ ns}$	/10 mA	
• BAT 41	100	100	0.1	50	{ 0.45 1 1 200	2	1			
• BAT 46	100	150	2	50	{ 0.25 0.1 0.45 10 1 250	6	1			
• BAT 49	80	500	200	80	{ 0.32 10 0.42 100 1 1000	120	0			DO41 GLASS
• BYV 10-20	20	1000	500	20	{ 0.55 1000 0.85 3000	220	0			MINIMELF GLASS
• BYV 10-30	30	1000	500	30	{ 0.55 1000 0.85 3000	220	0			
• BYV 10-40	40	1000	500	40	{ 0.55 1000 0.85 3000	220	0			
BYV 10-60	60	1000	500	60	{ 0.70 1000 1 3000	150	0			
• TMM BAT 42	30	200	0.5	25	{ 0.4 10 0.65 50 1 200	7	1	$t_{rr} < 5 \text{ ns}$	/10 mA	MINIMELF GLASS
• TMM BAT 43	30	200	0.5	25	{ 0.45 15 1 200	7	1	$\eta > 80\%$	/45 MHz	
TMM BAT 47	20	350	4	10	{ 0.25 0.1 0.4 10 1 300	12	1	$t_{rr} < 10 \text{ ns}$	/10 mA	
TMM BAT 48	40	350	2	10	{ 0.25 0.1 0.4 10 0.9 500	12	1	$t_{rr} < 10 \text{ ns}$	/10 mA	
TMM BAT 41	100	100	0.1	50	{ 0.45 1 1 200	2	1			
• TMM BAT 46	100	150	2	50	{ 0.25 0.1 0.45 10 1 250	6	1			
TM BAT 49	80	500	200	80	{ 0.32 10 0.42 100 1 1000	120	0			MELF GLASS
• TM BYV 10-20	20	1000	500	20	{ 0.55 1000 0.85 3000	220	0			MELF GLASS
TM BYV 10-30	30	10000	500	30	{ 0.55 1000 0.85 3000	220	0			
• TM BYV 10-40	40	1000	500	40	{ 0.55 1000 0.85 3000	200	0			
TM BYV 10-60	60	1000	500	60	{ 0.70 1000 1 3000	150	0			

• Preferred device.

 η : Detection efficiency.* Pulse test $t_p \leq 300 \mu\text{s}$, $\delta < 2\%$.